

V_{DSS}	1200V
$R_{DS(on)}$ (Typ.)	80mΩ
I_D	35A
P_D	179W

●Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Low V_{SD}
- 5) Easy to parallel
- 6) Simple to drive
- 7) Pb-free lead plating ; RoHS compliant

●Application

- Solar inverters
- DC/DC converters
- Induction heating
- Motor drives

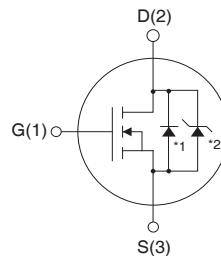
●Outline

TO-247



(1) (2) (3)

●Inner circuit



(1) Gate
(2) Drain
(3) Source

*1 Body Diode
*2 SBD

●Packaging specifications

Type	Packing	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	30
	Taping code	-
	Marking	SCH2080KE

●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	1200	V
Continuous drain current	I_D * ¹	35	A
	I_D * ¹	22	A
Pulsed drain current	$I_{D,pulse}$ * ²	80	A
Gate - Source voltage	V_{GSS}	-6 to 22	V
Power dissipation ($T_c = 25^\circ\text{C}$)	P_D	179	W
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C

● Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - case	R _{thJC}	-	-	0.7	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	50	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

● Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 1mA	1200	-	-	V
Zero gate voltage drain current	I _{DSS}	V _{DS} = 1200V, V _{GS} = 0V T _j = 25°C T _j = 150°C	- -	20 170	400 -	µA
Gate - Source leakage current	I _{GSS+}	V _{GS} = +22V, V _{DS} = 0V	-	-	100	nA
Gate - Source leakage current	I _{GSS-}	V _{GS} = -6V, V _{DS} = 0V	-	-	-100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 4.4mA	1.6	-	4.0	V
Static drain - source on - state resistance	R _{DS(on)} ^{*3}	V _{GS} = 18V, I _D = 10A T _j = 25°C T _j = 125°C	- -	80 125	117 -	mΩ
Gate input resistance	R _G	f = 1MHz, open drain	-	6.3	-	Ω

●Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Transconductance	g_{fs}^{*3}	$V_{DS} = 10\text{V}, I_D = 10\text{A}$	-	3.7	-	S
Input capacitance	C_{iss}	$V_{GS} = 0\text{V}$	-	1850	-	
Output capacitance	C_{oss}	$V_{DS} = 800\text{V}$	-	175	-	pF
Reverse transfer capacitance	C_{rss}	$f = 1\text{MHz}$	-	20	-	
Turn - on delay time	$t_{d(on)}^{*3}$	$V_{DD} = 400\text{V}, V_{GS} = 18\text{V}$	-	37	-	
Rise time	t_r^{*3}	$I_D = 10\text{A}$	-	33	-	
Turn - off delay time	$t_{d(off)}^{*3}$	$R_L = 40\Omega$	-	70	-	
Fall time	t_f^{*3}	$R_G = 0\Omega$	-	28	-	

●Gate Charge characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	Q_g^{*3}	$V_{DD} = 400\text{V}$	-	106	-	
Gate - Source charge	Q_{gs}^{*3}	$I_D = 10\text{A}$	-	27	-	nC
Gate - Drain charge	Q_{gd}^{*3}	$V_{GS} = 18\text{V}$	-	31	-	
Gate plateau voltage	$V_{(plateau)}$	$V_{DD} = 400\text{V}, I_D = 10\text{A}$	-	9.7	-	V

*1 Limited only by maximum temperature allowed.

*2 PW $\leq 10\mu\text{s}$, Duty cycle $\leq 1\%$

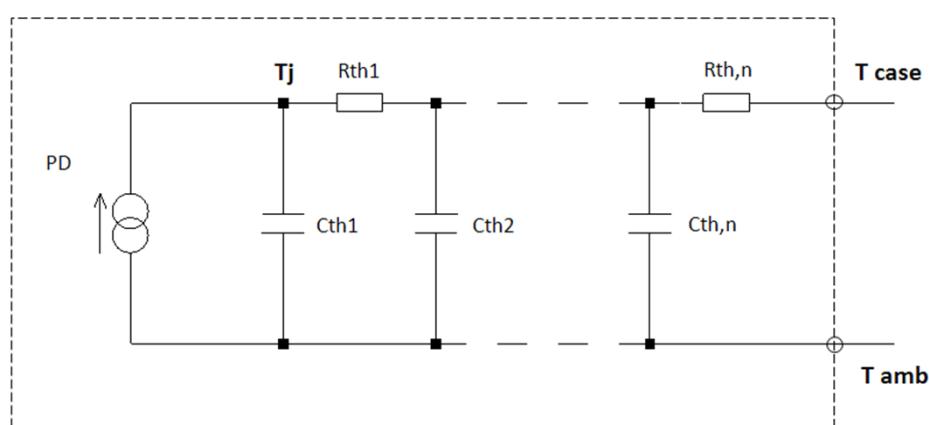
*3 Pulsed

● Body diode electrical characteristics (Source-Drain) ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Inverse diode continuous, forward current	I_S^{*1}	$T_c = 25^\circ\text{C}$	-	-	35	A
Inverse diode direct current, pulsed	I_{SM}^{*2}		-	-	80	A
Forward voltage	V_{SD}^{*3}	$V_{GS} = 0\text{V}, I_S = 10\text{A}$	-	1.3	-	V
Reverse recovery time	t_{rr}^{*3}	$I_F = 10\text{A}, V_R = 400\text{V}$ $\text{di/dt} = 150\text{A}/\mu\text{s}$	-	37	-	ns
Reverse recovery charge	Q_{rr}^{*3}		-	60	-	nC
Peak reverse recovery current	I_{rrm}^{*3}		-	2.4	-	A

● Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R_{th1}	0.098	K/W	C_{th1}	0.005	Ws/K
R_{th2}	0.237		C_{th2}	0.032	
R_{th3}	0.212		C_{th3}	0.666	



● Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

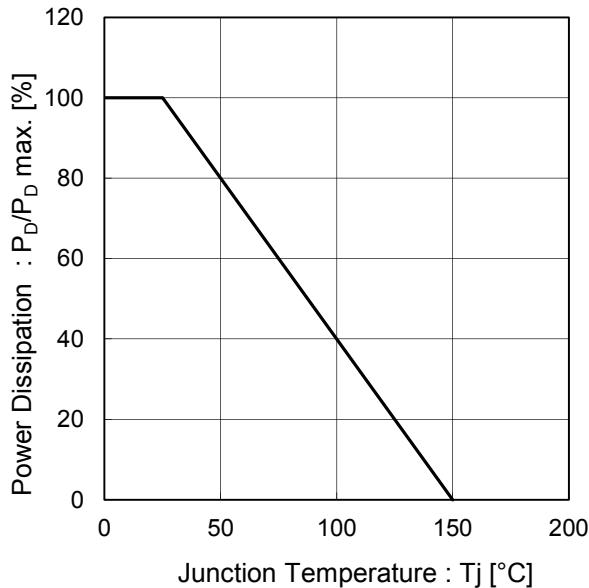


Fig.2 Maximum Safe Operating Area

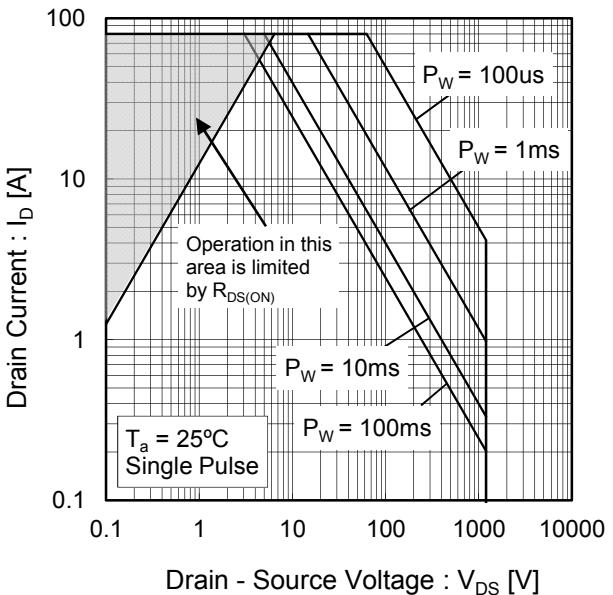
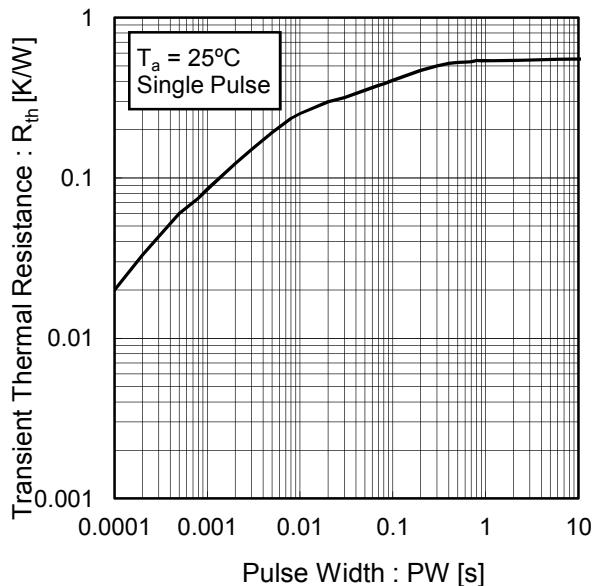


Fig.3 Typical Transient Thermal Resistance vs. Pulse Width



●Electrical characteristic curves

Fig.4 Typical Output Characteristics(I)

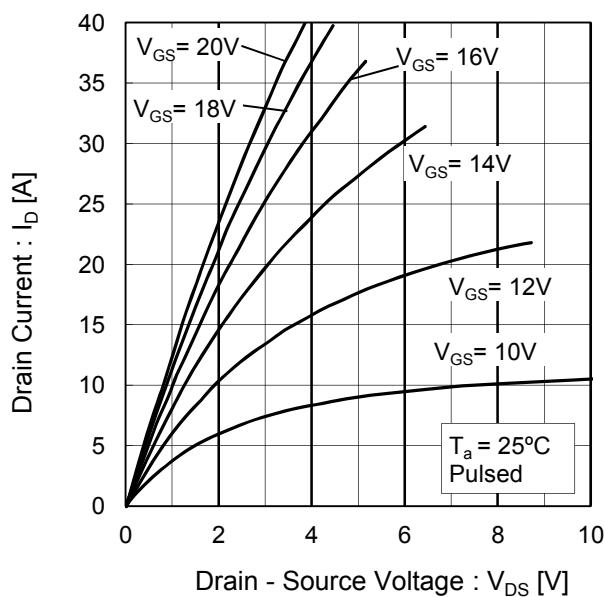


Fig.5 Typical Output Characteristics(II)

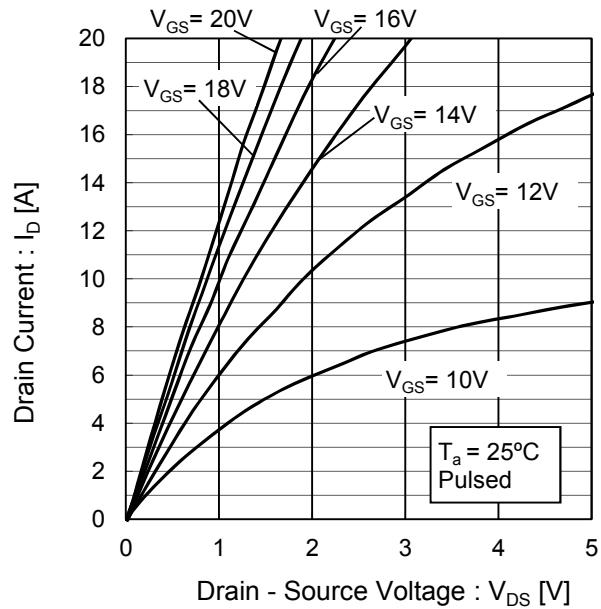


Fig.6 $T_j = 150^\circ\text{C}$ Typical Output Characteristics(I)

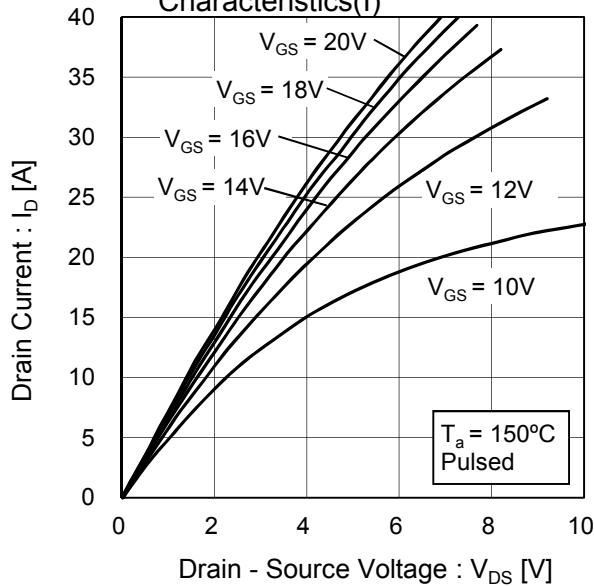
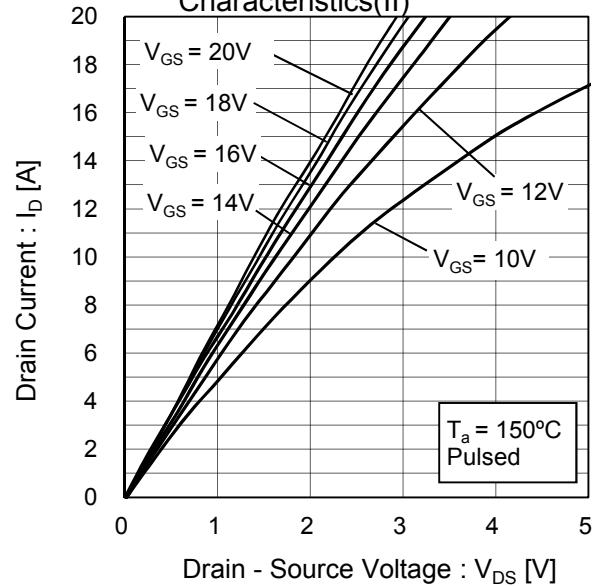


Fig.7 $T_j = 150^\circ\text{C}$ Typical Output Characteristics(II)



●Electrical characteristic curves

Fig.8 Typical Transfer Characteristics

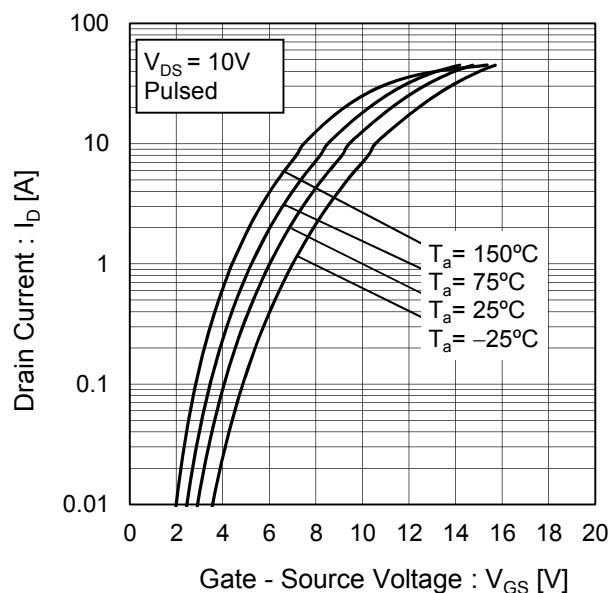


Fig.9 Gate Threshold Voltage vs. Junction Temperature

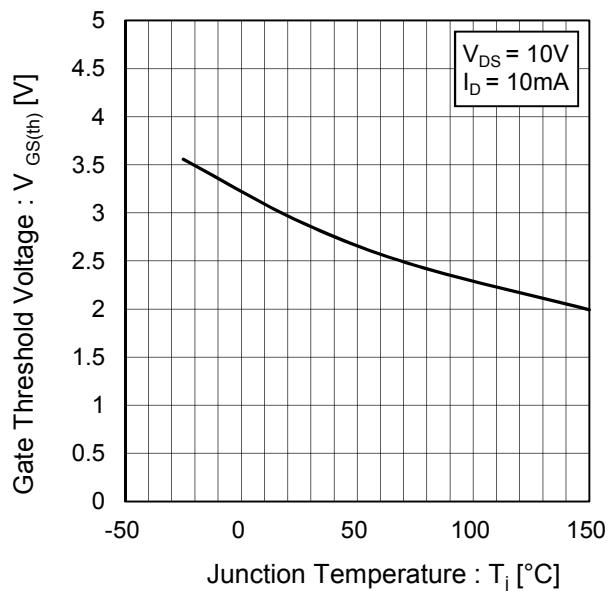
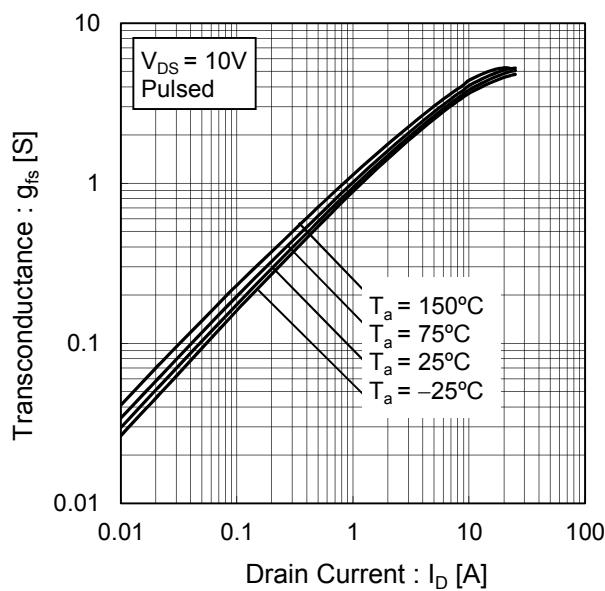


Fig.10 Transconductance vs. Drain Current



●Electrical characteristic curves

Fig.11 Static Drain - Source On - State
Resistance vs. Gate - Source Voltage

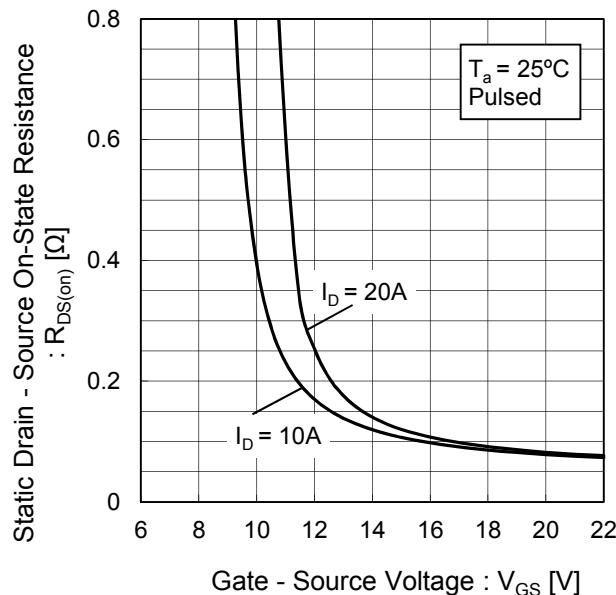


Fig.12 Static Drain - Source On - State
Resistance vs. Junction Temperature

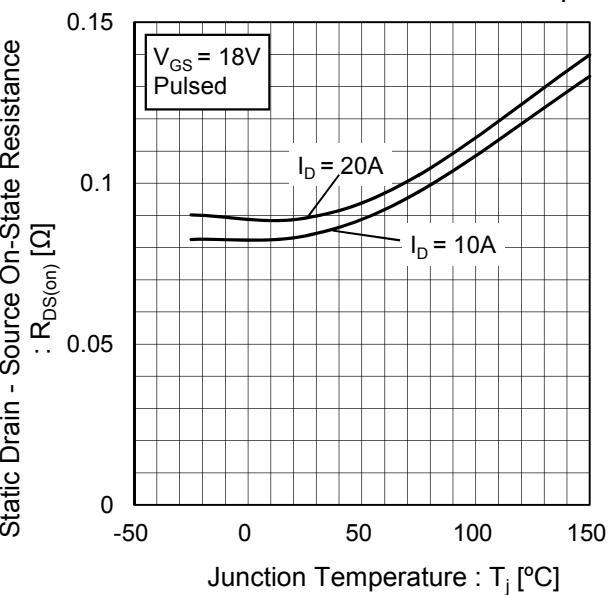
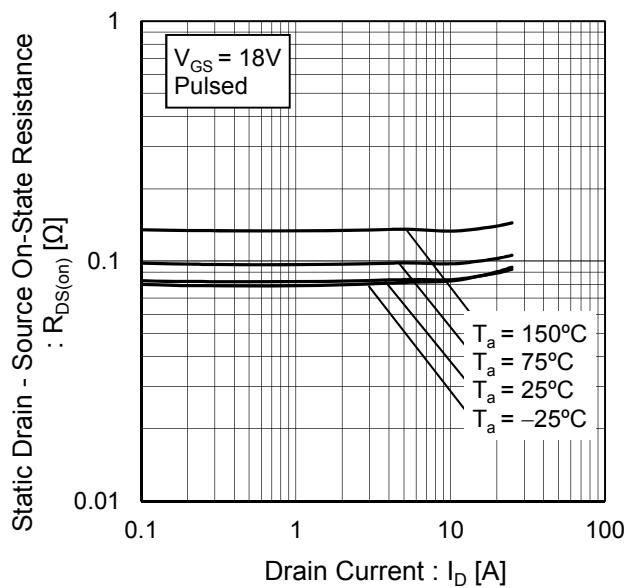


Fig.13 Static Drain - Source On - State
Resistance vs. Drain Current



●Electrical characteristic curves

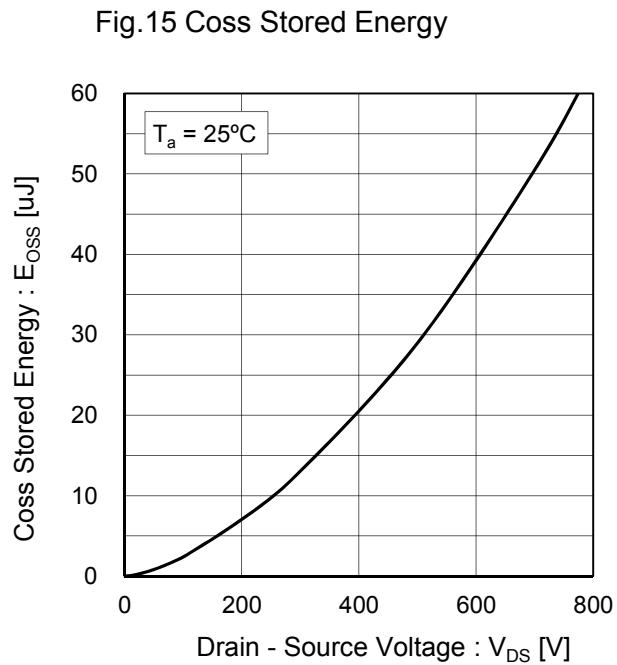
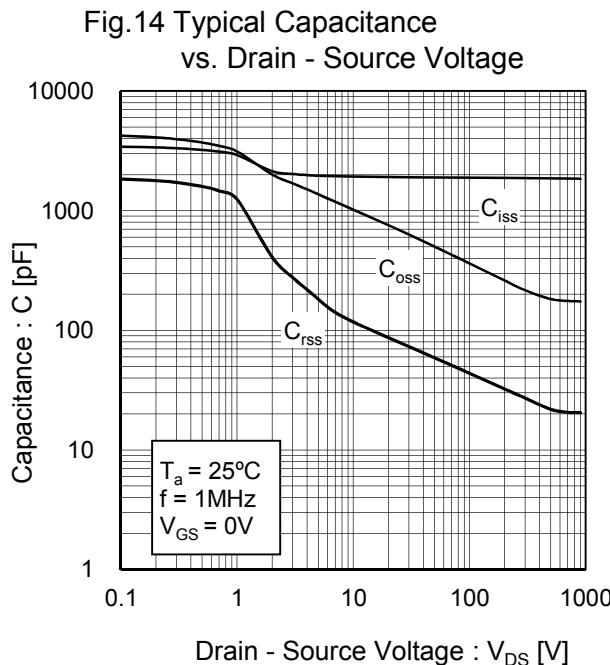


Fig.16 Switching Characteristics

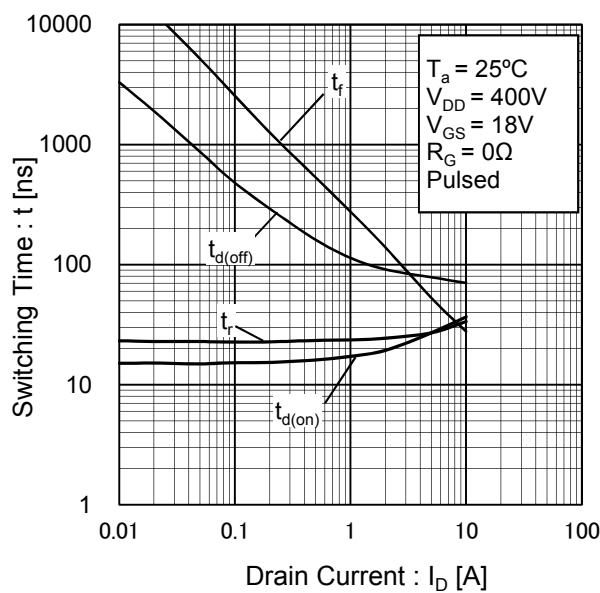
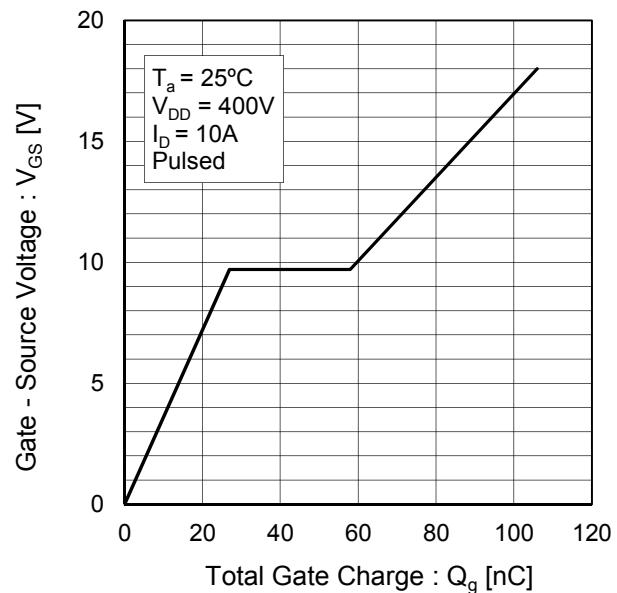


Fig.17 Dynamic Input Characteristics



●Electrical characteristic curves

Fig.18 Inverse Diode Forward Current vs. Source - Drain Voltage

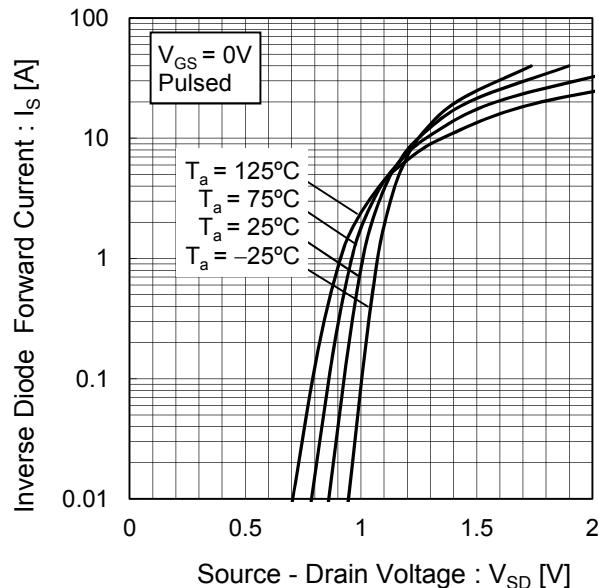
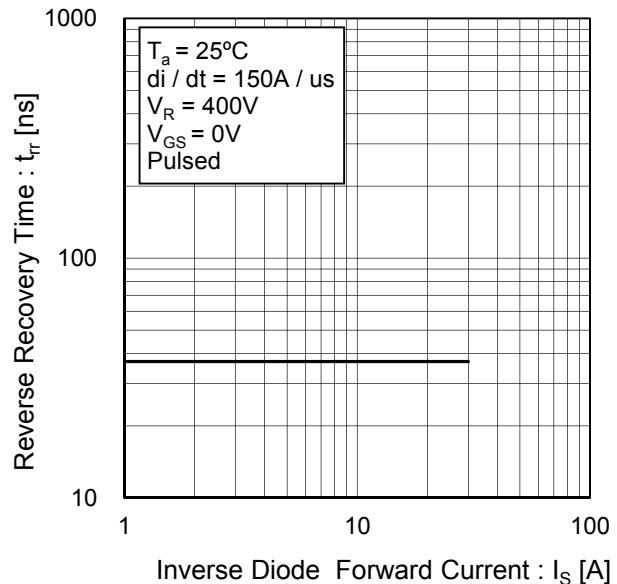


Fig.19 Reverse Recovery Time vs.Inverse Diode Forward Current



●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

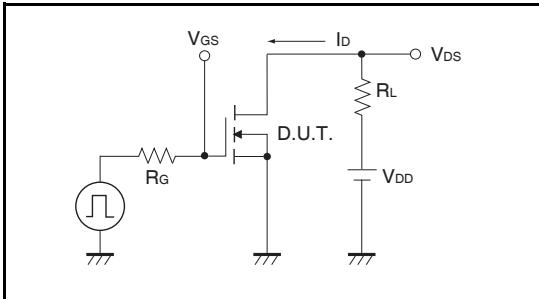


Fig.1-2 Switching Waveforms

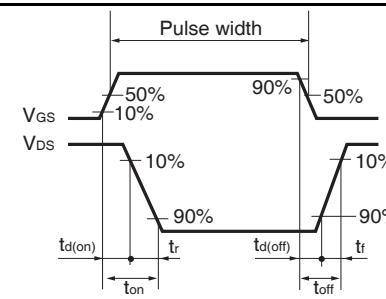


Fig.2-1 Gate Charge Measurement Circuit

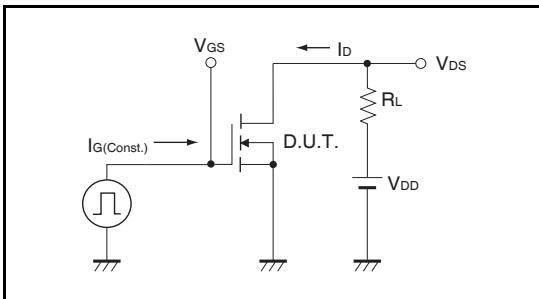


Fig.2-2 Gate Charge Waveform

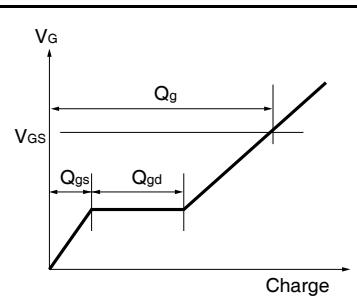


Fig.3-1 di/dt Measurement Circuit

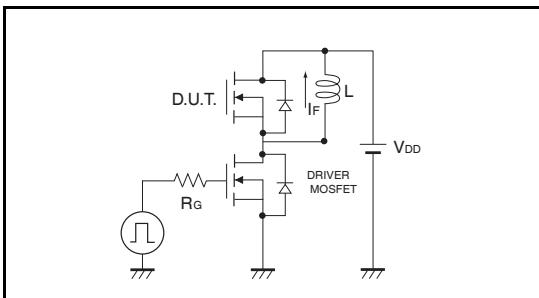
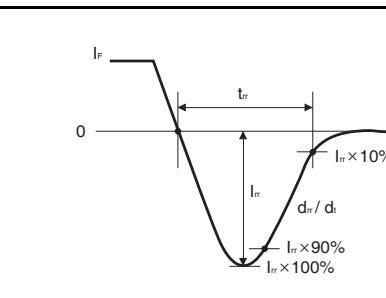
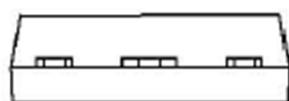
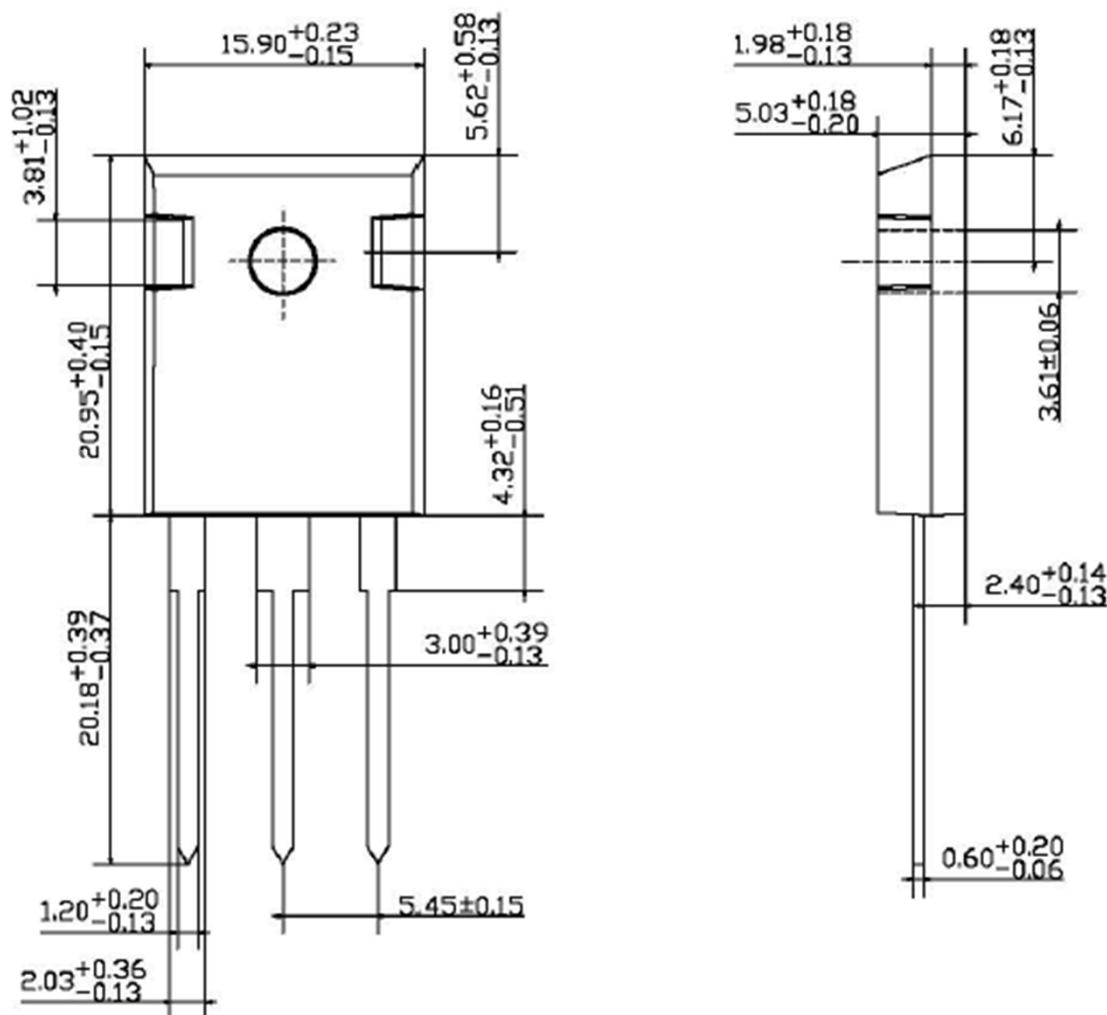


Fig.3-2 di/dt Waveform



●Dimensions (Unit : mm)

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Notes

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